Vishay General Semiconductor

# Surface-Mount Ultrafast Plastic Rectifier



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SMC (DO-214AB) Cathode O Anode

## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	3.0 A				
V <sub>RRM</sub>	100 V, 150 V, 200 V				
t <sub>rr</sub>	25 ns				
V <sub>F</sub>	0.90 V				
T <sub>J</sub> max.	175 °C				
Package	SMC (DO-214AB)				
Circuit configuration	Single				

## **FEATURES**

- Glass passivated pellet chip junction
- · Ideal for automated placement
- Ultrafast recovery times for high efficiency

ESH3B-M3, ESH3C-M3, ESH3D-M3

- Low forward voltage, low power loss
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## **TYPICAL APPLICATIONS**

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer, and automotive.

## **MECHANICAL DATA**

Case: SMC (DO-214AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT
Device marking code		EHB	EHC	EHD	
Maximum repetitive peak reverse voltage	V <sub>RMM</sub>	100	150	200	
Maximum RMS voltage	V <sub>RMS</sub>	70	105	140	V
Maximum DC blocking voltage	V <sub>DC</sub>	100	150	200	
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub>	3.0			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	125			A
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175			°C



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage	I <sub>F</sub> = 3 A		V <sub>F</sub> <sup>(1)</sup>	0.90	V	
Maximum DC reverse current	7	T <sub>A</sub> = 25 °C		5.0		
at rated DC blocking voltage		T <sub>A</sub> = 125 °C	IR	150	μΑ	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	25		
Typical reverse recovery time	IF = 074, VR = 00 V,	T <sub>J</sub> = 25 °C	- t <sub>rr</sub>	40	ns	
		T <sub>J</sub> = 100 °C		55		
Typical stored charge	I <sub>F</sub> = 3 A, V <sub>B</sub> = 30 V,	$T_{\rm J} = 3$ A, $V_{\rm B} = 30$ V, $T_{\rm J} = 25$ °C	0	25	nC	
	dl/dt = 50 A/µs, I <sub>rr</sub> = 10 % I <sub>RM</sub> T <sub>J</sub> = 100 °C	T <sub>J</sub> = 100 °C	Q <sub>rr</sub>	60		
Typical junction capacitance	4.0 V, 1 MHz		CJ	70	pF	

#### Note

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT
Typical thermal resistance	R <sub>0JA</sub> <sup>(1)</sup>	50			°C/W
rypical mermanesistance	R <sub>θJL</sub> <sup>(1)</sup>	15			

### Note

<sup>(1)</sup> Units mounted on PCB with 12.0 mm x 12.0 mm land areas

ORDERING INFORMATION (Example)							
PREFERRED P/N	ERRED P/N UNIT WEIGHT (g) PREFERRED PACKAGE CODE		BASE QUANTITY	DELIVERY MODE			
ESH3D-M3/57T	0.211	57T	850	7" diameter plastic tape and reel			
ESH3D-M3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel			



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## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

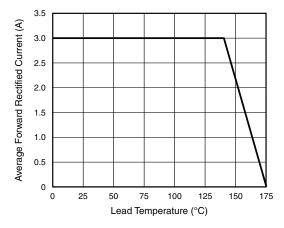


Fig. 1 - Maximum Forward Current Derating Curve

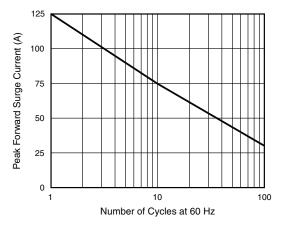


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

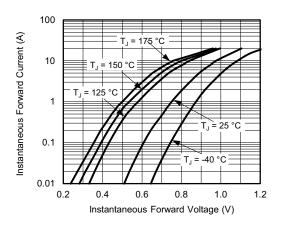


Fig. 3 - Typical Instantaneous Forward Characteristics

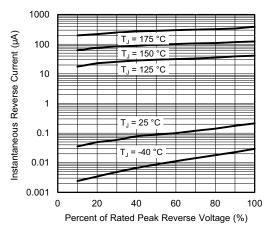


Fig. 4 - Typical Reverse Leakage Characteristics

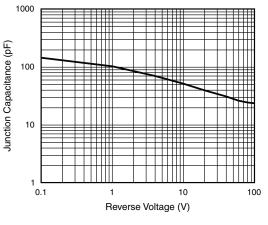


Fig. 5 - Typical Junction Capacitance

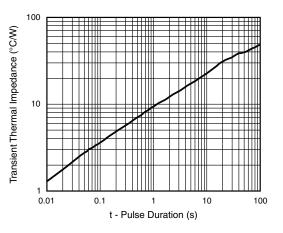


Fig. 6 - Typical Transient Thermal Impedance

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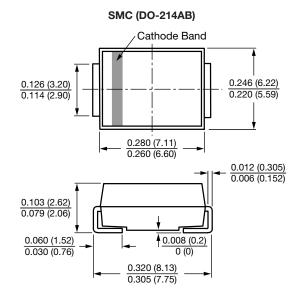


# ESH3B-M3, ESH3C-M3, ESH3D-M3

**Mounting Pad Layout** 

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## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



0.126 (3.20) MIN.



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